Electronic Supplementary Information

Phase transformation of ultrathin nanowires through lanthanide doping: from InOOH to rh-In₂O₃

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Experimental details

Materials. Indium(III) chloride tetrahydrate (InCl₃·4H₂O), gadolinium(III) chloride hydrate (GdCl₃·xH₂O), indium(III) acetylacetonate (In(acac)₃), gadolinium(III) acetylacetonate (Gd(acac)₃), oleylamine (OM, 70%) were purchased from Sigma-Aldrich and used as starting materials without further purification.

Synthesis of nanocrystals. The InOOH precursors were prepared by a solvothermal route firstly reported by Xu and Wang.¹ In a typical procedure, 0.1 g $InCl_3 \cdot 4H_2O$ and 0 g or 0.0065 g GdCl₃·xH₂O ($n_{Gd}/n_{In+Gd}=5\%$) was dissolved in 5 mL of OM. Then, 8 mL of ethanol was dropped in while ultrasonicating, forming a clear solution, which was transferred into a Teflon-lined stainless steel autoclave to react at 180 °C for 12 h. The product was collected at the bottom, washed three times with ethanol, and centrifuged at 5000 rpm for 2 min. The white product can be well redispersed in cyclohexane.

When the chlorides were replaced by acetylacetonates as raw materials, 0.1405 g $In(acac)_3$ and 0 g or 0.0082 g $Gd(acac)_3$ ($n_{Gd}/n_{In+Gd}=5\%$) were used and other procedures were the same as described above. The Gd-doped product can be well redispersed in cyclohexane.

To transform InOOH to In_2O_3 , the as-synthesized InOOH precursors redispersed in 1 ml cyclohexane was heated in 10 ml OM at 100 °C for 30 min, then degased at 100 °C for 30 min and subsequently heated at 250 or 300 °C for 30 min under Ar atmosphere. The product was washed three times with ethanol and collected by centrifugation at 5000 rpm for 2 min.

Characterization. JEM 1400 transmission electron microscope (TEM) operated at 120 kV was used to record TEM images of the samples. Scanning transmission electron microscopy (STEM) and high-resolution TEM (HRTEM) images were taken with FEI Tecnai F20 with an attached energy dispersed X-ray spectrometer (EDS). Powder X-ray diffraction (XRD) analyses were performed on a Philips PW-1830 X-ray diffractometer with Cu K α irradiation ($\lambda = 1.5406$ Å) at a scanning speed of 0.014 degree/sec over the 2 θ range of 10–70 degree. The photoluminescence (PL) spectroscopic measurements were performed on a LabRam HR spectrometer (JY-Horiba) with He-Cd laser as the excitation source (λ_{ex} = 325 nm).



Figure S1 Crystal unit cell of (a) InOOH (H is not included for clarification), (b) $c-In_2O_3$ and (c) rh-In_2O_3 viewed along the b axes.

Reference

1 X. X. Xu and X. Wang, Inorg. Chem., 2009, 48, 3890.